

Shottky barrier diode

RB495D

●Application

General rectification.

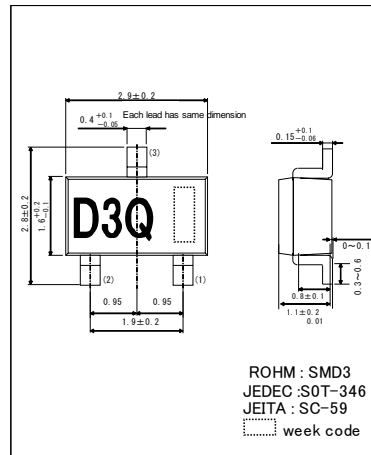
●Features

- 1) Small mold type. (SMD3)
- 2) Low Ir
- 3) High reliability.

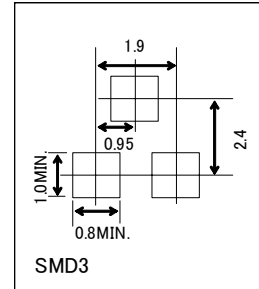
●Structure

Silicon epitaxial planar

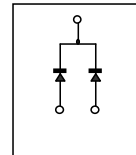
●External dimensions (Unit : mm)



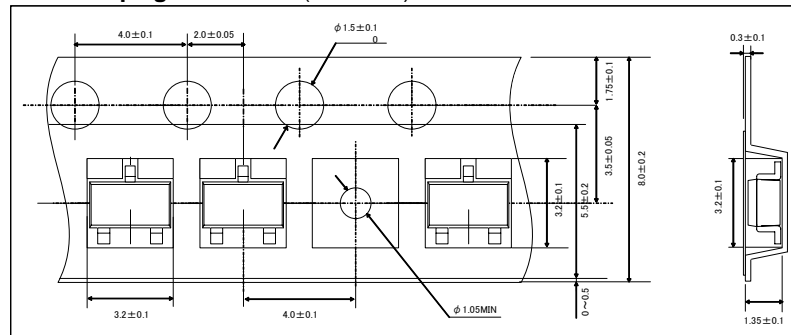
●Lead size figure (Unit : mm)



●Structure



●Taping dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Reverse voltage (repetitive peak)	V_{RM}	40	V
Reverse voltage (DC)	V_R	25	V
Average rectified forward current (*1)	I_o	0.4	A
Forward current surge peak (60Hz · 1cyc)	I_{FSM}	2	A
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-40 to +125	°C

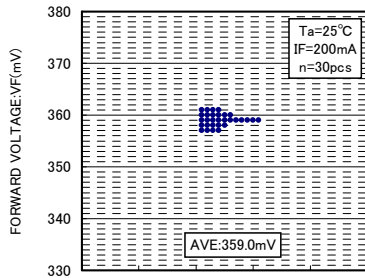
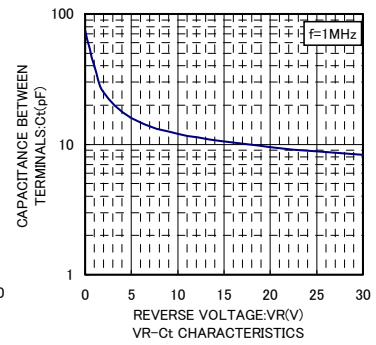
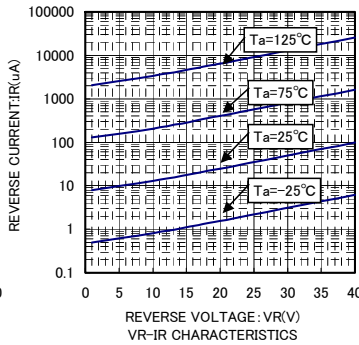
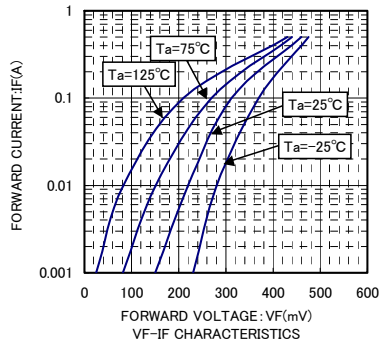
(*1)Rating of per diode : $I_o/2$

●Electrical characteristics (Ta=25°C)

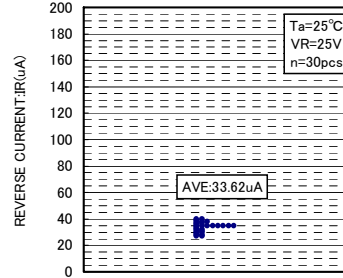
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{F1}	-	-	0.30	V	$I_F=10mA$
	V_{F2}	-	-	0.50	V	$I_F=200mA$
Reverse current	I_{R1}	-	-	70	μA	$V_R=25V$

Diodes

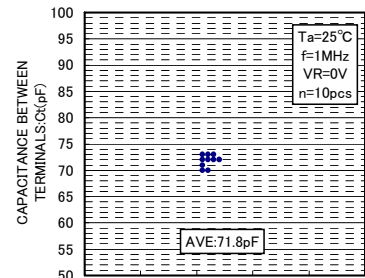
●Electrical characteristic curves (Ta=25°C)



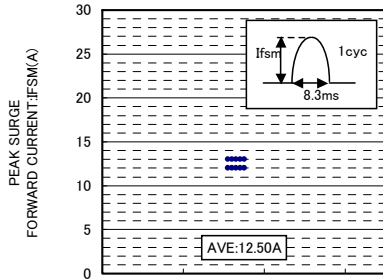
VF DISPERSION MAP



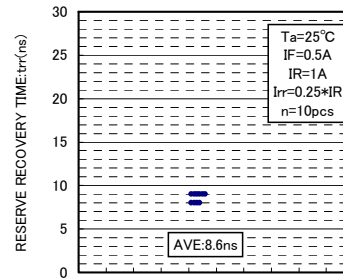
IR DISPERSION MAP



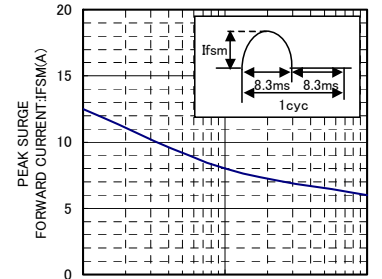
Ct DISPERSION MAP



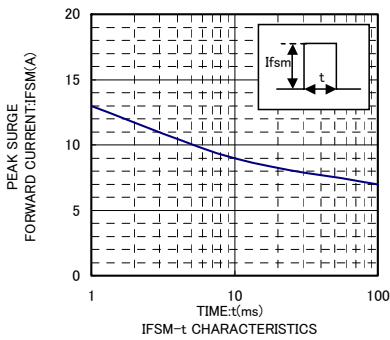
IFSM DISERSION MAP



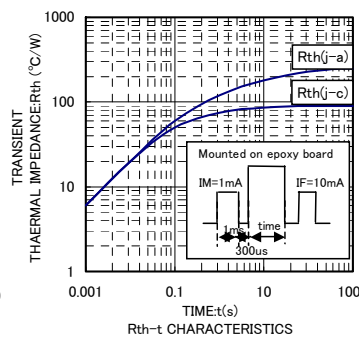
trr DISPERSION MAP



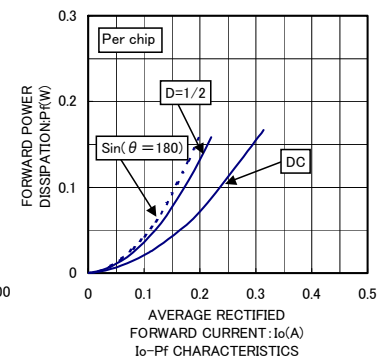
IFSM-CYCLE CHARACTERISTICS



IFSM-t CHARACTERISTICS

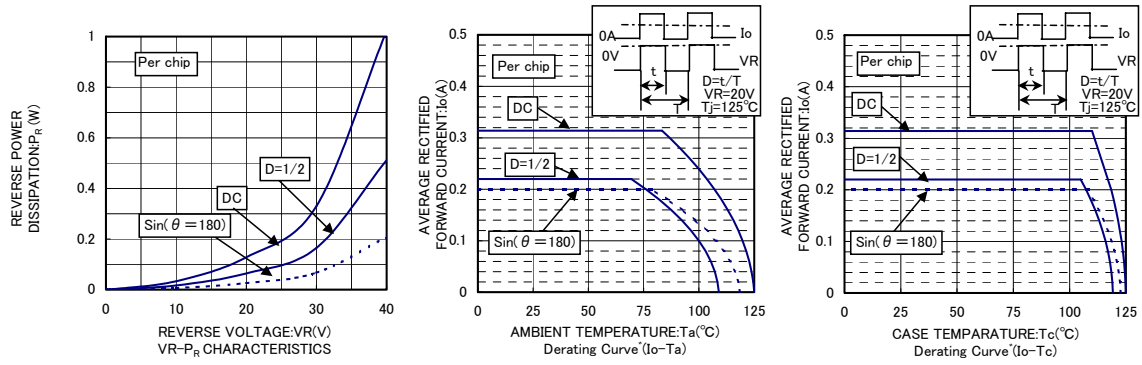


Rth-t CHARACTERISTICS



Io-Pf CHARACTERISTICS

Diodes



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